





FZT7053

Features

- $BV_{CEO} > 100V$ •
- $BV_{CBO} > 100V$
- I_C = 1.5A High Continuous Current
- hFE > 10k for very High Gain @100mA
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

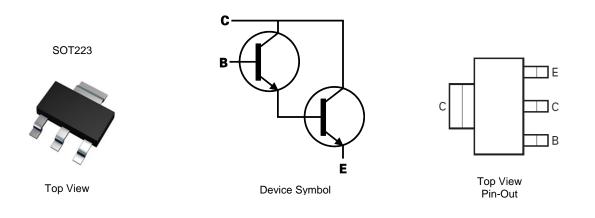
100V NPN DARLINGTON TRANSISTOR IN SOT223

Mechanical Data

- Case: SOT223 •
- Case material: Molded Plastic. "Green" Molding Compound; • UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

- Lamp
- Relay
- Solenoid Driving



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT7053TA	FZT7053	7	12	1,000
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.				

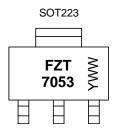
(OHS 2) ompliant. All ap oHS exempti

2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http:// www.diodes.com/products/packages.html.

Marking Information



FZT 7053 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	12	V
Continuous Collector Current	lc	1.5	А
Peak Pulse Current	I _{CM}	2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Power Dissipation (Note 6)	PD	1.25	W
Power Dissipation (Note 7)	PD	2	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	125	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	100	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _θ JA	62	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R _{θJL}	19.4	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

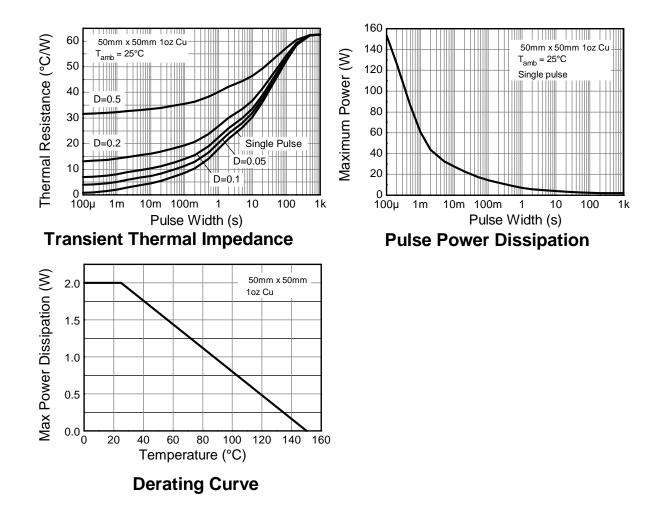
Notes:

5. For a device surface mounted on 15mm x 14mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is a device surface induited of 15mm 14 from x 15mm 144 FCB with high coverage of s measured when operating in a steady-state condition.
Same as Note 5, except the device is surface mounted on 25mm x 25mm with 1oz copper.
Same as Note 5, except the device is surface mounted on 50mm x 50mm with 1oz copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).





Thermal Characteristics and Derating Information







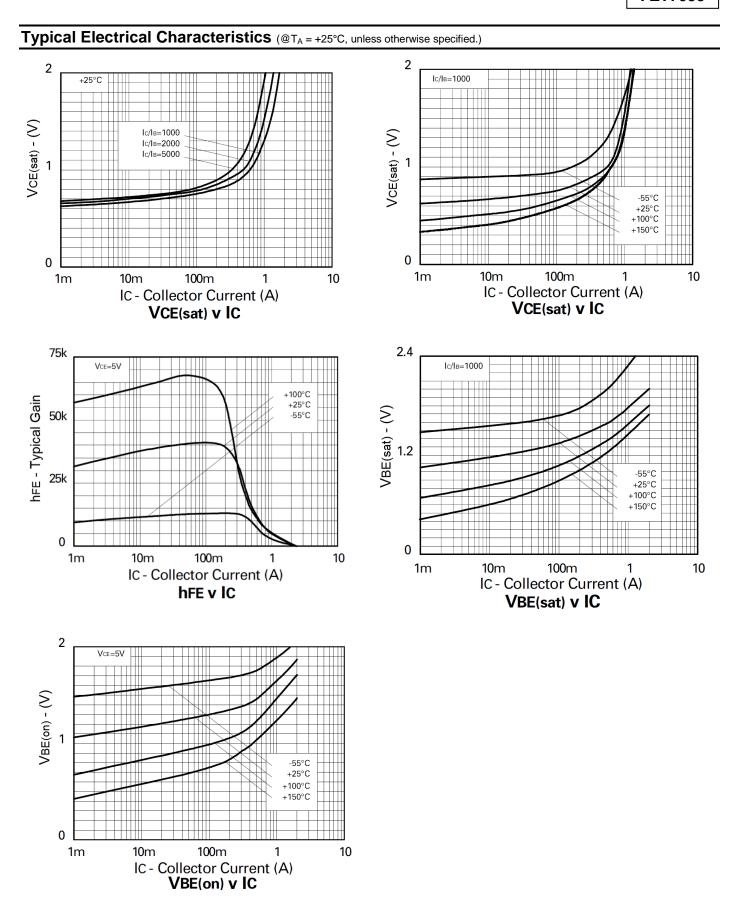
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	300	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	100	130	-	V	$I_{\rm C} = 1 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	12	14	-	V	I _E = 100μA
Collector-Base Cut-Off Current	I _{CBO}	-	<10	100	nA	V _{CB} = 80V
Collector-Emitter Cut-Off Current	ICES	-	<10	200	nA	V _{CE} = 80V
Emitter Cut-Off Current	I _{EBO}	-	<10	100	nA	V _{EB} = 7V
DC Current Gain (Note 9)	h _{FE}	10,000 1,000	-	-	-	$I_{C} = 100 \text{mA}, V_{CE} = 5 \text{V}$ $I_{C} = 1 \text{A}, V_{CE} = 5 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	-	-	1.5	V	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 0.1 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	-	2.0	V	I _C = 100mA, V _{CE} = 5V
Output Capacitance (Note 9)	C _{obo}	-	6.0	8.0	pF	V _{CB} = 10V. f = 1MHz
Current Gain-Bandwidth Product (Note 9)	f _T	200	-	-	MHz	$V_{CE} = 5V, I_{C} = 100mA$
Turn-On Time	t _{on}	-	0.7	-	μs	V _{CC} = 10V, I _C = 100µA
Turn-Off Time	t _{off}	-	2.5	-	μs	$I_{B1} = -I_{B2} = 0.1 \text{mA}$

9. Measured under pulsed conditions. Pulse width ≤ 300 $\mu s.$ Duty cycle ≤ 2%. Note:





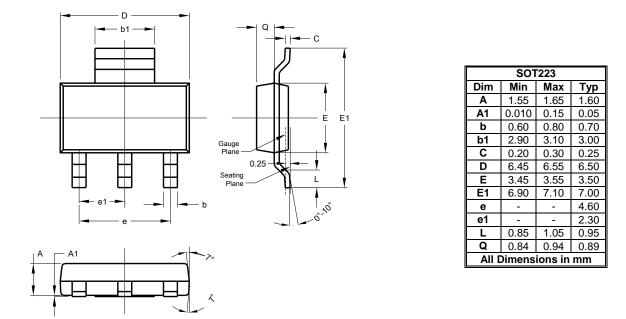






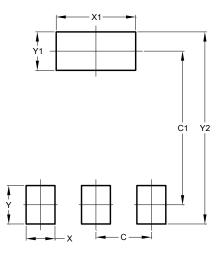
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00





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